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I, Nikhil, certify that the work embodied in this thesis is my own bonafide work and carried out by me under the supervision of *Prof. Rajiv Prakash* from July 2016 to June 2022 at the School of Materials Science & Technology, Indian Institute of Technology, Banaras Hindu University, Varanasi. The matter embodied in this thesis has not been submitted for the award of any other degree/diploma. I declare that I have faithfully acknowledged and given credits to the research workers wherever their works have been cited in my work in this thesis. I further declare that I have not willfully copied any other's work, paragraphs, text, data, results, etc., reported in journals, books, magazines, reports, dissertations, theses, etc., or available at websites and have not included them in this thesis and have not cited as my own work.

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It is certified that the above statement made by the student is correct to the best of my knowledge.

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### Acknowledgement

The work presented in this thesis would not have been possible without my close association with many peoples who were always there when I needed them the most. I take this opportunity to acknowledge them and extend my sincere gratitude for helping me make this thesis a possibility. At this moment of accomplishment, first of all I would like to pay the homage to the founder of Banaras Hindu University, Pandit Madan Mohan Malvia ji, who made this glorious temple to realize spiritual, technical and scientific knowledge about this vast existing universe.

I embrace the opportunity to express my deep sense of gratitude to my supervisor **Dr. Rajiv Prakash**, Professor, School of Materials Science & Technology, IIT (B.H.U.), Varanasi for his constant guidance, valuable suggestions and kind encouragement during my association with his research group. His encouragement, constant support, intellectual stimulation, perceptive guidance, immensely valuable ideas, and suggestions from the initial to the final level enabled me to develop an understanding of the subject. His scholarly suggestions, prudent admonitions, immense interest, constant help and affectionate behavior have been a source of inspiration for me. His suggestions will remain with me as an inexhaustible source of scientific learning throughout my life.

I would like to express my sincere and whole hearted gratitude to **Prof. P. Maiti, Dr. A. K. Singh, Dr. C. Rath, Dr. C. Upadhyay, Dr. B. N. Pal, Dr. Ashish kumar Mishra, Dr. Sanjay Singh Dr. Shravan kumar Mishra. And Dr. Nikhil** (School of Materials Science and Technology, IIT-BHU, Varanasi) for discussion during seminars and valuable suggestions given by them. I am indeed obliged and sincerely thankful to my RPEC member **Dr.Indrajeet Sinha**, Department of Chemistry, IIT- BHU for his guidance and untiring attention right from the inception to the successful completion of assigned research work. Most of the results described in this thesis would not have been obtained without a close collaboration with few laboratories.. I am thankful to the unknown reviewers who have rejected my papers several times in some of the international conferences and journals. The comments that they provided helped to polish our articles in better shape. But the bigger and nobler cause of thanking them is that the rejections have equipped me with high level of patience and helped me a lot to exercise/implement my spiritual thoughts in practice.

My acknowledgement will never be complete without the special mention of my lab seniors who have taught me the lab culture and have lived by example to make me understand the hard facts of life. I would like to acknowledge, Dr. Gopal Ji, Dr. Monika Srivastava, Dr. Rajiv kumar Pandey, Dr. Arun K. Singh, Dr. Akhilesh K. Singh, Dr. Ashish Kumar, Dr. Uday Pratap Azad, Dr. Narsingh Raw Nirala, Dr. Neeraj Giri, Dr. Madhu Tiwari, Dr. Kashish, Dr. Preeti Tiwari, Dr.Chandrajeet verma, Dr.Vinita, Dr. Richa Mishra, Dr.Manish Kumar Singh for all their support and motivation during the initial days of my PhD. I can see my thesis in the good shape because of his help in formatting the entire thesis. I express my special thanks to my senior **Dr. Praveen Kumar Sahu** for his guidance, support, motivation and valuable suggestions. Also I am thankful to my lab fellows and juniors of my lab specially Ankit Verma, Saurabh, Radhe Shyam, , Ravi, Vineet, Aniruddha, Shweta, Priya, Nupur, Ajay, Rajpal, Shubhajit, for their helping behavior. I am also thankful to all, to whom I could not mention here who helped me directly or indirectly throughout the work. I am thankful to all nonteaching staff of SMST, IIT (BHU) and CIFC for their cooperation at all levels.

I express my indebtedness to my parents Smt. Kiran Bala and Sri. Raj Bahadur, my sisters Dimple, Pooja for their love, affection and support during every moment in my life.

I gratefully acknowledge the MHRD and CSIR New Delhi for providing me the necessary funding and fellowship to pursue research work.

(Nikhil)

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# LIST OF ABBREVIATIONS

AC	Activated carbon
AFM	Atomic Force Microscopy
Al	Aluminum
Aq.	Aqueous
Au	Gold
BET	Brunauer-Emmet-Teller
СВ	Conduction band
CHCl <sub>3</sub>	Chloroform
CNT	Carbon nanotube
CV	Cyclic voltammetry
DPV	Differential pulse voltammetry
DI	Deionised water
EIS	Electrochemical impedance spectroscopy
Eq.	Equation
FESEM	Field emmision scanning electron microscopy
Fig.	Figure
FTIR	Fourier transform infrared spectroscopy
FTM	Floating Film Transfer methods
GCE	Glassy carbon electrode
GO	Graphene oxide
GQDs	Graphene quantum dots
Gr	Graphite
НОМО	Highest Occupied Molecular Orbital.
HRSEM	High Resolution Scanning Electron Microscopy
HRTEM	High resolution transmission electron microscopy
ITO	Indium Tin Oxide

### LIST OF ABBREVIATIONS

KPFM	Kelvin probe force microscopy
LB	Langmuir Blodgett
LOD	Limit of detection
LOQ	Limit of Quantification
LS	Langmuir Schaefer
LUMO	Lowest Unoccupied Molecular Orbital
MW	Molecular Weight
nm	Nanometer
OFET	Organic Field Effect Transistor
РА	Polyacetylene
PBS	Phosphate buffer solution
PBTTT	Poly(2,5-bis(3-alkylthiophen-2-yl)thieno[3,2-b]thiophene)
РЗНТ	Poly(3-hexylthiophene
РРу	Polypyrrole
PQT-12	Poly (3, 3 <sup>**</sup> -dialkylquarterthiophene)
РТ	polythiophene
rGO	reduced Graphene Oxide
ROX	3-nitro-4-hydroxyphenyl arsonic acid
$\mathbb{R}^2$	Regression coefficient value
rr P3AT	regioregular poly (3-aklylthiophene)
SAED	Selected Electron Diffraction pattern
SD	Standard Deviation
Sec	Second
SEM	Scanning Electron Microscopy
S/N	Signal to noise ratio

# LIST OF ABBREVIATIONS

SPGE	Screen printed graphite electrode
TEM	Transmission electron microscopy
UV-Vis	Ultraviolet- Visible
XRD	X-ray diffraction
XPS	X-ray photoelectron spectroscopy
d	interplanar spacing
eV -	electron volt
θ	theta
υ	scan rate
R	Gas constant
Т	Temperature
V	Volt
μA	Microampere
μΜ	Micromolar
Si	Silicon
SiO <sub>2</sub>	Silicon dioxide
2-D	Two dimensional
3-D	Three dimensional